UNION CARBIDE CORP. POLYSILICON STATUS AND PLANS

JET PROPULSION LABORATORY

M.H. Leipold

UCC Silane-to-Silicon Process

SEQUENCE OF PROCESS STEPS

- SILANE SYNTHESIS
 - HYDROCHLORINATION:

Si(MG) + 3SiCl4 + H4 = 4HSiCl3

- REMOVE METAL IMPURITIES AS CHLORIDES

2H2SiCl2 = SiH4 + SiCl4

- DISTILLATION/PURIFICATION OF SiH4 AND CHLOROSILANES
- SILICON CONVERSION (SiH4 TO Si)
 - FLUIDIZED-BED SI DEPOSITION ON SEED PARTICLES (FREE-FLOWING SI PARTICLES > 300 \(\mu M \)
 - FREE SPACE REACTOR PYROLYSIS AND THEN MELTING/ SHOTTING (> 2 MM SHOT)
- RECYCLING OF H2 AND SICI4

PARTICIONA PACE DISCUIRDO POR POSACIO

Contract Progress

- CONTRACT (#954334) STARTED OCTOBER, 1975
- PROCESS FEASIBILITY EXPERIMENTALLY DEMONSTRATED
- SILANE/SILICON PROCESS DESIGN COMPLETED
- COST ESTIMATES INDICATE CAPABILITY OF MEETING THE <\$14/KG (1980 \$) Si PRICE GOAL
- SILANE SYNTHESIS APPROACH WELL ESTABLISHED
 - NEEDS TO BE TESTED IN CONTINUOUS STEADY-STATE
 OPERATION OF EPSDU (EXPERIMENTAL PROCESS SYSTEM DEVELOPMENT UNIT)
 - ENGINEERING DESIGN COMPLETED
 - EQUIPMENT FOR EPSDU FABRICATED
 - CIVIL CONTRACT AT EAST CHICAGO UCC SITE COMPLETED
 - JPL/DOE FUNDING FOR SILANE SYNTHESIS EPSDU STOPPED BEFORE MECHANICAL AND ELECTRICAL INSTALLATIONS
- CONVERSION OF SILANE TO SILICON:
 - FLUIDIZED-BED APPROACH APPEARS PROMISING, BUT NEEDS FURTHER R & D. EFFORT WILL CONTINUE UNDER DOE/JPL CONTRACT
 - FREE-SPACE REACTOR APPROACH IS LESS FAVORABLE.
 MAJOR PROBLEMS IN POWDER HANDLING, MELTING, SHOTTING OPERATION AND PURITY CONTROL
- CONTRACT MODIFICATIONS ARE UNDERWAY. THESE ARE EXPECTED TO RESULT IN UCC OPERATING EPSDU AT THEIR EXPENSE WITH PERFORMANCE RESULTS AVAILABLE TO DOE/JPL

PLENARY SESSION: M.H. LEIPOLD

Status: UCC Plans for Polysilicon Production

 ON MAY 1, 1981, UCC ANNOUNCED ITS INTENTION TO BUILD A 1000 MT/YR COMMERCIAL POLY SI PLANT IN WASHINGTON STATE.
 DESIGN TO BE BASED ON THE DATA FROM THE SILANE EPSDU;
 KOMATSU (SIEMENS TYPE) DEPOSITION REACTORS

 EPSDU EQUIPMENT MOVED (FROM EAST CHICAGO) AND BEING INSTALLED IN WASHOUGAL, WASHINGTON. THIS IS A UCC PILOT PLANT PROJECT. OPERATION EXPECTED IN FALL 1982 (USING KOMATSU REACTORS)

Future Activities and Prospects

- ADVANCED SILANE SYNTHESIS TECHNOLOGY (FBR) TO BE TESTED IN PILOT PLANT AT UCC ELECTRONIC MATERIALS TEST CENTER AS FINAL PHASE OF JPL/DOE R & D INVESTIGATION
- THE DEVELOPMENT OF SILANE/SILICON PROCESS CONTINUES
 TOWARD PROVIDING A LOW-COST POLY SI TECHNOLOGY.
 ALTHOUGH MANY FUNDING/SCHEDULE CLANGES OCCURRED, THE
 SUCCESSFUL CONTINUATION OF THIS PROGRAM SHOWS THAT THIS
 APPROACH REPRESENTS AN EFFECTIVE WAY OF CONDUCTING
 COOPERATIVE ENERGY R & D BY THE INDUSTRY AND THE
 GOVERNMENT
- FSA/DOE GOAL OF < \$14/KG SILICON CAN ONLY BE ACHIEVED BY SILANE/SILICON PROCESS WHICH INCORPORATES NEW TECHNOLOGY DEPOSITION REACTOR SUCH AS FBR BEING INVESTIGATED